

SKiiP 1813 GB123-3DL V3



SKiiP® 3

2-pack-integrated intelligent Power System

SKiiP 1813 GB123-3DL V3

Features

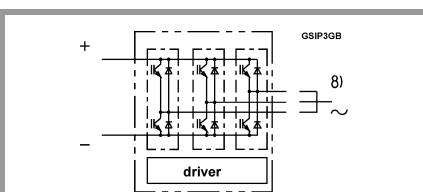
- SKiiP technology inside
- Trench IGBTs
- CAL HD diode technology
- Integrated current sensor
- Integrated temperature sensor
- Integrated heat sink
- UL recognized File no. E63532

Typical Applications*

- Renewable energies
- Traction
- Elevators
- Industrial drives

Footnotes

¹⁾ With assembly of suitable MKP capacitor per terminal



S33

Absolute Maximum Ratings		$T_s = 25^\circ\text{C}$ unless otherwise specified		
Symbol	Conditions	Values	Unit	
System				
$V_{CC}^{1)}$	Operating DC link voltage	900	V	
V_{isol}	DC, $t = 1\text{ s}$, main terminals to heat sink	4300	V	
$I_{t(RMS)}$	per AC terminal, $T_{terminal} < 115^\circ\text{C}$	400	A	
I_{FSM}	$T_j = 150^\circ\text{C}$, $t_p = 10\text{ ms}$, $\sin 180^\circ$	10200	A	
I^2t	$T_j = 150^\circ\text{C}$, $t_p = 10\text{ ms}$, diode	520	kA^2s	
f_{out}	fundamental output frequency	1	kHz	
T_{stg}	storage temperature	-40 ... 85	$^\circ\text{C}$	
IGBT				
V_{CES}	$T_j = 25^\circ\text{C}$	1200	V	
I_C	$T_j = 150^\circ\text{C}$	$T_s = 25^\circ\text{C}$	1695	A
		$T_s = 70^\circ\text{C}$	1306	A
I_{Cnom}		1800	A	
T_j	junction temperature	-40 ... 150	$^\circ\text{C}$	
Diode				
V_{RRM}	$T_j = 25^\circ\text{C}$	1200	V	
I_F	$T_j = 150^\circ\text{C}$	$T_s = 25^\circ\text{C}$	1411	A
		$T_s = 70^\circ\text{C}$	1068	A
I_{Fnom}		1410	A	
T_j	junction temperature	-40 ... 150	$^\circ\text{C}$	
Driver				
V_s	power supply	13 ... 30	V	
V_{iH}	input signal voltage (high)	15 + 0.3	V	
$V_{isolIPD}$	QPD $\leq 10\text{pC}$, PRIM to POWER	1170	V	
dv/dt	secondary to primary side	75	$\text{kV}/\mu\text{s}$	
f_{sw}	switching frequency	10	kHz	

Characteristics		$T_s = 25^\circ\text{C}$ unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Unit
IGBT					
$V_{CE(sat)}$	$I_C = 900\text{ A}$ at terminal	$T_j = 25^\circ\text{C}$	1.7	2.1	V
		$T_j = 125^\circ\text{C}$	1.9		V
V_{CE0}		$T_j = 25^\circ\text{C}$	0.90	1.10	V
		$T_j = 125^\circ\text{C}$	0.80	1.00	V
r_{CE}	at terminal	$T_j = 25^\circ\text{C}$	0.9	1.1	$\text{m}\Omega$
		$T_j = 125^\circ\text{C}$	1.2	1.5	$\text{m}\Omega$
$E_{on} + E_{off}$	$I_C = 900\text{ A}$ $T_j = 125^\circ\text{C}$	$V_{CC} = 600\text{ V}$	331		mJ
		$V_{CC} = 900\text{ V}$	585		mJ
$R_{th(j-s)}$	per IGBT switch			0.02	K/W
$R_{th(j-r)}$	per IGBT switch			0.018	K/W

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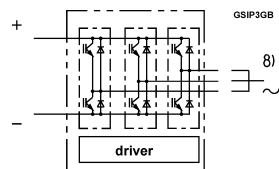
Typical Applications*

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Footnotes

¹⁾ With assembly of suitable MKP capacitor per terminal

Characteristics		$T_s = 25^\circ\text{C}$ unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Unit
Diode					
$V_F = V_{EC}$	$I_F = 900\text{ A}$ at terminal	$T_j = 25^\circ\text{C}$	1.50	1.80	V
		$T_j = 125^\circ\text{C}$	1.50		V
V_{F0}		$T_j = 25^\circ\text{C}$	0.9	1.10	V
		$T_j = 125^\circ\text{C}$	0.7	0.90	V
r_F	at terminal	$T_j = 25^\circ\text{C}$	0.7	0.8	m Ω
		$T_j = 125^\circ\text{C}$	0.9	1	m Ω
E_{rr}	$I_F = 900\text{ A}$ $T_j = 125^\circ\text{C}$	$V_R = 600\text{ V}$	63		mJ
		$V_R = 900\text{ V}$	84		mJ
$R_{th(j-s)}$	per diode switch			0.038	K/W
$R_{th(j-r)}$	per diode switch			0.058	K/W
Driver					
V_s	supply voltage non stabilized	13	24	30	V
I_{SO}	bias current @ $V_s=24\text{V}$, $f_{sw} = 0$, $I_{AC} = 0$		300		mA
I_s	$k_1 = 42\text{ mA/kHz}$, $k_2 = 0.00044\text{ mA/A}^2$	= 300	$+ k_1 * f_{sw} + k_2 * I_{AC}^2$		mA
V_{IT+}	input threshold voltage (HIGH)	12.3			V
V_{IT-}	input threshold voltage (LOW)			4.6	V
R_{IN}	input resistance		10		k Ω
C_{IN}	input capacitance		1		nF
t_{pRESET}	error memory reset time		0.0122		ms
t_{TD}	top / bottom switch interlock time		3		μs
t_{jitter}	jitter clock time		125		ns
t_{SIS}	short pulse suppression time		0.625	0.7	μs
I_{TRIPSC}	over current trip level	2205	2250	2295	A_{PEAK}
T_{trip}	over temperature trip level	110	115	120	$^\circ\text{C}$
V_{DCtrip}	over voltage trip level,		not impl.		V
$t_{d(on)O}$	$V_{CC} = 900\text{ V}$ $I_C = 900\text{ A}$ $T_j = 25^\circ\text{C}$	input-output turn-on propagation time	1.4		μs
$t_{d(off)O}$		input-output turn-off propagation time	1.4		μs
System					
$R_{th(r-a)}$	flow rate=420m ³ /h, $T_a=25^\circ\text{C}$, 500m above sea level			0.0294	K/W
R_{CC+EE}	terminals to chip, $T_s = 25^\circ\text{C}$		0.17		m Ω
L_{CE}	commutation inductance		4		nH
C_{CHC}	per phase, AC-side		5.1		nF
$I_{CES} + I_{RD}$	$V_{GE} = 0\text{ V}$, $V_{CE} = 1200\text{ V}$, $T_j = 25^\circ\text{C}$		3.6		mA
M_{dc}	DC terminals, SI Units	6		8	Nm
M_{ac}	AC terminals, SI Units	13		15	Nm
w	SKiiP System w/o heat sink		2.4		kg
w_h	heat sink		6.2		kg



S33

Isolation coordination acc. to EN 50178 and IEC 61800-5-1

Maximum grid RMS voltage, line-to-line, grounded delta mains	480V+20%
Installation altitude for maximum grid RMS voltage, line-to-line, grounded delta mains	2000m
Maximum grid RMS voltage, line-to-line, star point grounded mains	480V+20%
Installation altitude for maximum grid RMS voltage, line-to-line, star point grounded mains	5000m
Maximum transient peak voltage between low voltage circuit and mains	1600V
Pollution degree acc. to IEC 60664-1 outside the moulded power section	2
Overvoltage cat. acc. to IEC 60664-1 for mains	III
Basic isolation	between heat sink and mains; between low voltage circuit and mains
Protection level acc. to IEC 60529	IP00

Environmental conditions acc.to IEC 60721

	Storage	Transportation	Operation stationary use at weather protected locations	Operating ground vehicle installations	Operating ship environment
Climatic conditions	1K2 ₍₁₎	2K2 ₍₁₎	3K3 ₍₁₎	5K1 ₍₁₎	---
Biological conditions	1B1	2B1	3B1	5B1	6B1
Chemically active substances (excluded: salt spray)	1C2	2C1	3C2	5C2	6C2
Mechanically active substances	1S1	2S1	3S1	5S1	6S1
Mechanical conditions	1M3	(4)	3M6 ₍₂₎	5M3 ₍₃₎	6M3
Contaminating fluids	---	---	---	5F1	---

(1) expanded temperature range: -40°C / +85°C. Please note: by operation near 85°C the life time of product is reduced.

(2) 3M7 possible, but due to the mechanic load capacity of external components like DC-Link capacitors limited to 3M6

(3) 5M3 without impact of foreign bodies, stones

(4) no declaration due to customer-specific packing

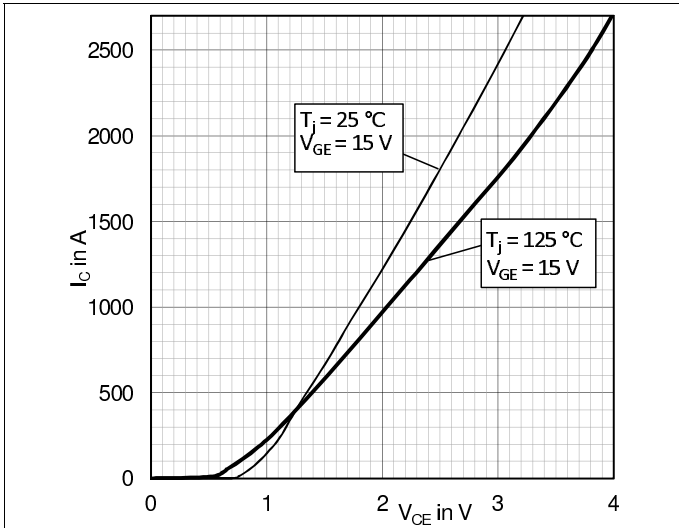


Fig. 1: Typical IGBT output characteristic

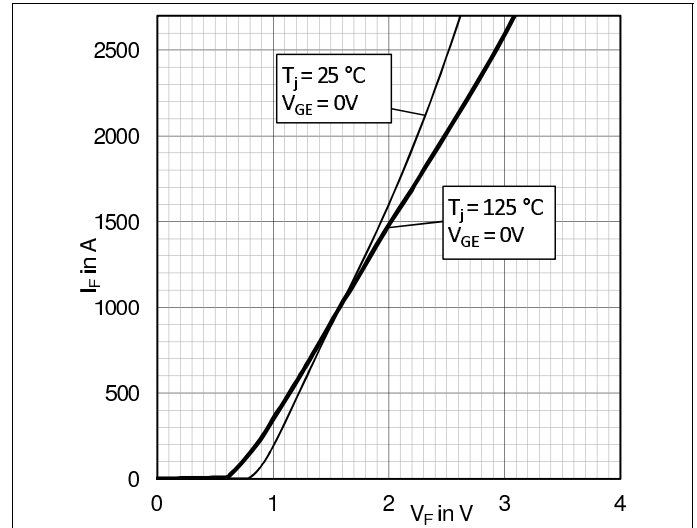


Fig. 2: Typical diode output characteristics

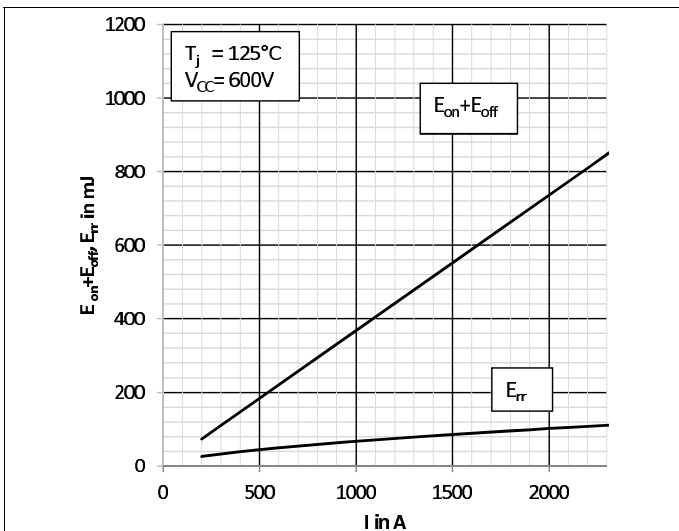


Fig. 3: Typical energy losses $E = f(I_C, V_{CC})$

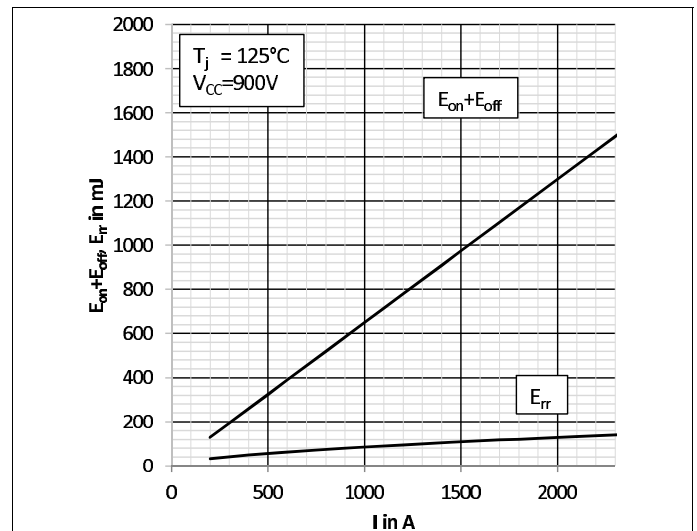


Fig. 4: Typical energy losses $E = f(I_C, V_{CC})$

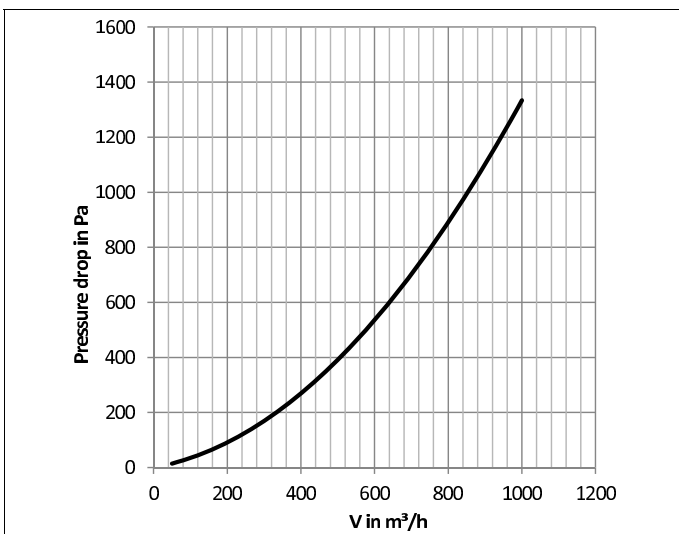


Fig. 5: Pressure drop Δp versus flow rate V

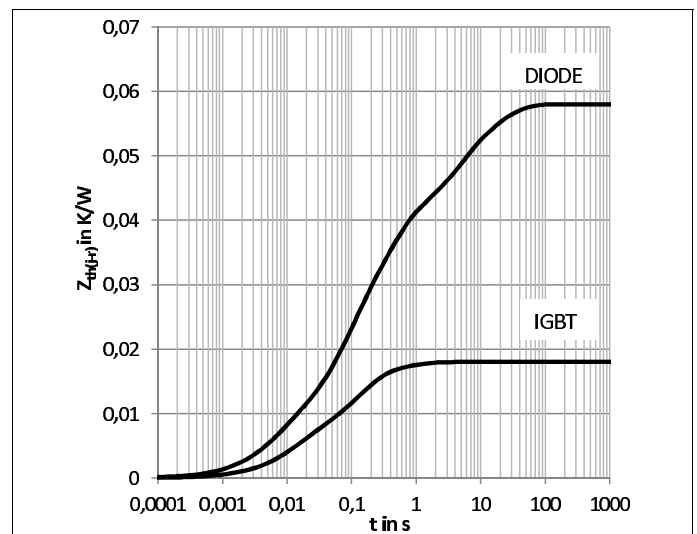


Fig. 6: Transient thermal impedance $Z_{th(j-r)}$

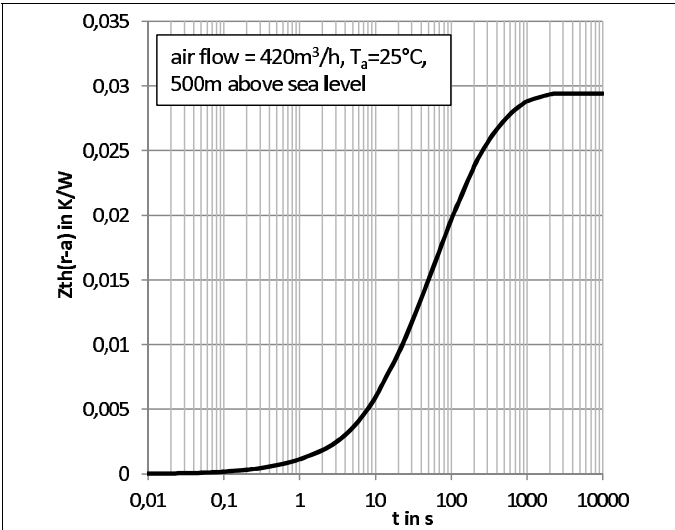


Fig. 7: Transient thermal impedance $Z_{th}(r-a)$

		$R_{th} [K/W]$				
		1	2	3	4	5
$Z_{th(j-r)} I$		0,0056	0,0101	0,0023	0,0000	0,0000
$Z_{th(j-r)} D$		0,0070	0,0152	0,0174	0,0112	0,0072
$Z_{th(r-a)}$		0,0005	0,0044	0,0078	0,0100	0,0067
		$\tau [s]$				
		1	2	3	4	5
$Z_{th(j-r)} I$		0,0120	0,1200	0,6000	1,0000	1,0000
$Z_{th(j-r)} D$		0,0060	0,0700	0,3400	4,4000	20,000
$Z_{th(r-a)}$		0,4700	11,000	40,000	105,00	410,00

Fig. 8: Coefficients of thermal impedances

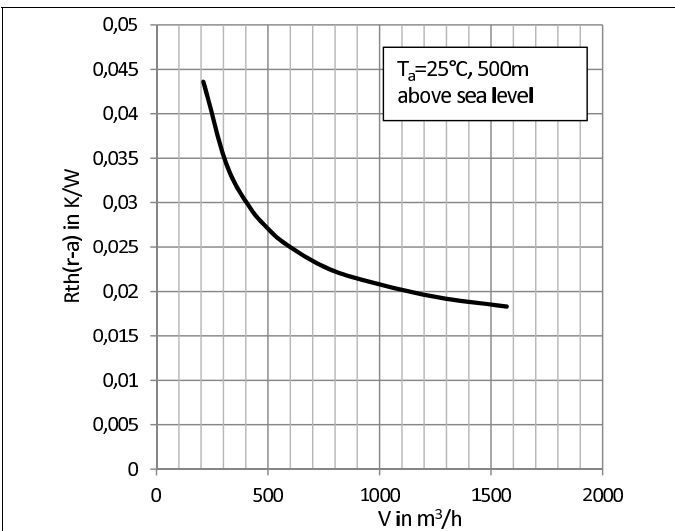
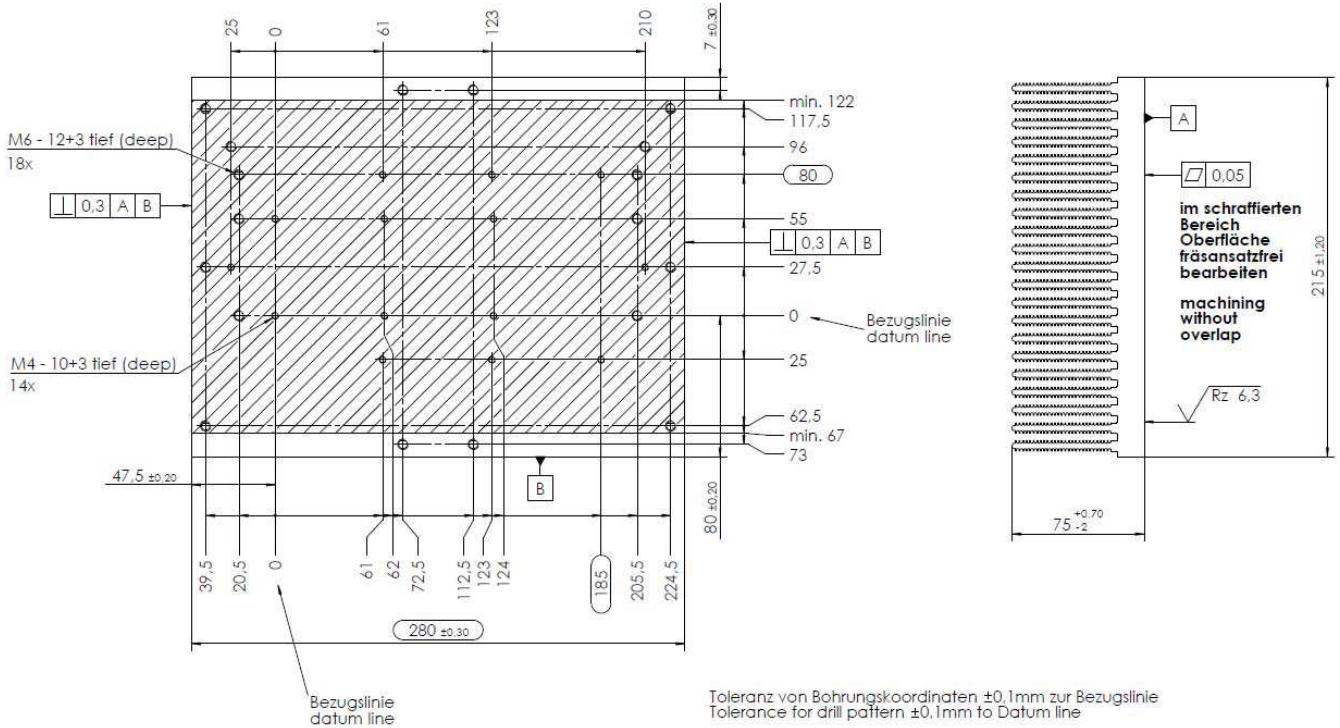


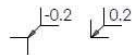
Fig. 9: Thermal resistance $R_{th}(r-a)$ versus flow rate V

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Control dimension

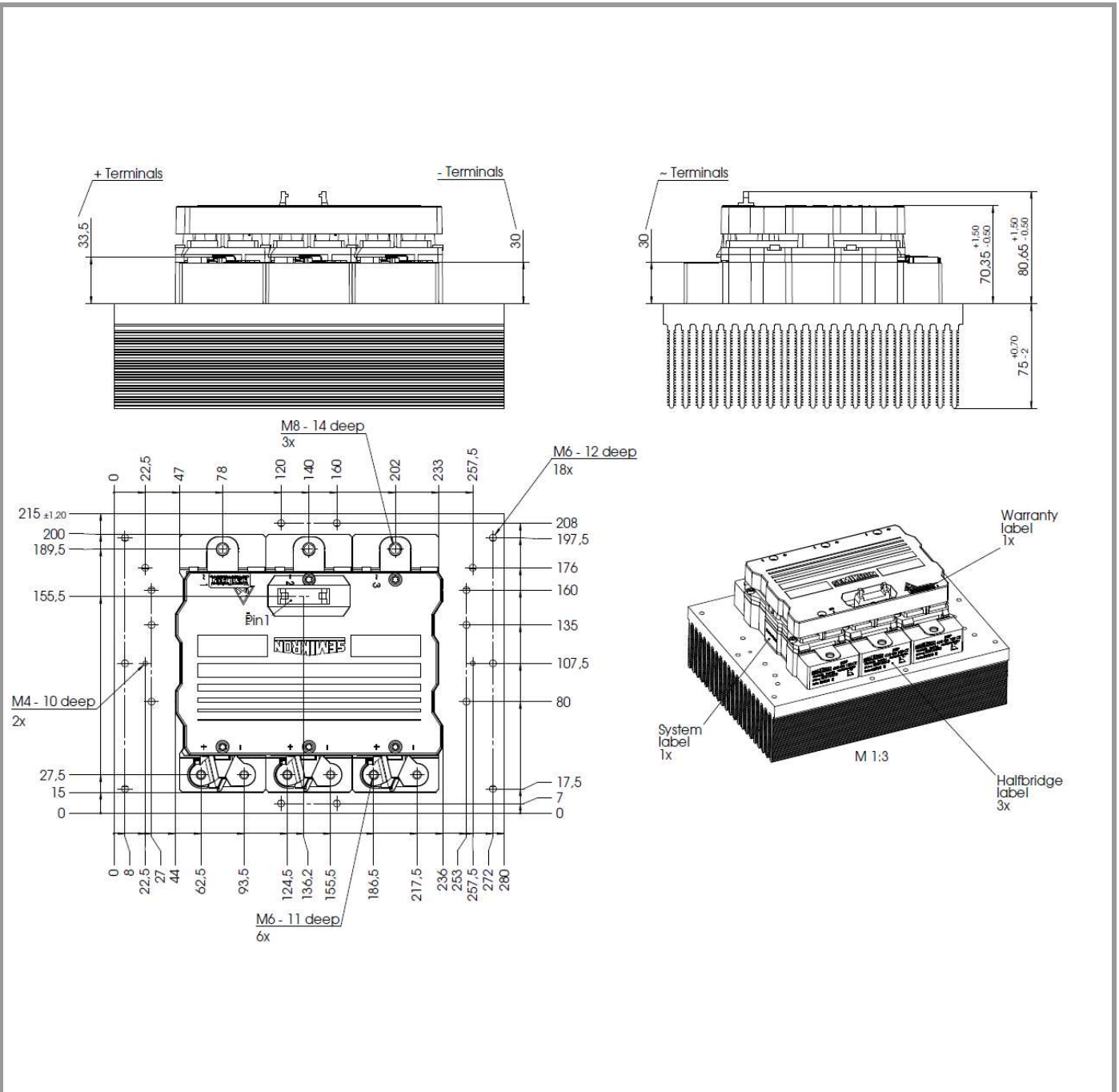
edge of workpiece DIN ISO 13715



- fettfrei nach DIN 53364 ≥ 32 mN/m
- Surface, threads and holes must be grease and oil free

Heat sink

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System

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX

* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our staff.